

Overview**Parametric Product Search****Silicon Photodiodes**

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Avalanche Photodiodes (APD)

Ultra High Gain Silicon Photodetectors

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Silicon Avalanche Photodiodes make use of internal multiplication to achieve gain due to impact ionization. The result is the optimized series of high Responsivity devices, exhibiting excellent sensitivity. OSI Optoelectronics offers several sizes of detectors that are available with flat windows or ball lenses for optical fiber applications.

**Product Applications**

- High Speed Optical Communications
- Laser Range Finder
- Bar Code Readers
- Optical Remote Control
- Medical Equipment
- High Speed Photometry

Product Features

- High Speed Responsivity / QE
- High Bandwidth / Fast Response
- Low Noise
- Low Bias Voltage
- Hermetically Sealed TO-Packages

Silicon Avalanche Photodiodes (APD)

Model Number	Active Area	Active Area Dimensions	Peak Wavelength	Responsivity	Dark Current (Max)	Terminal Capacitance	Breakdown Voltage Typ. (100µA)	Temperature Coefficient of Breakdown Voltage	Gain (800 nm)	Package	Click Image to Zoom
APD02-8-150-T52	.03 mm ²	0.2 Φ mm	800 nm	50 A/W	1 nA	1.5 pF	150 V	.45 V/°C	100	65 / TO-52 or 66 / TO-52L	
APD05-8-150-T52	.19 mm ²	.5 Φ mm	800 nm	50 A/W	1 nA	3 pF	150 V	.45 V/°C	100	65 / TO-52 or 66 / TO-52L	
APD10-8-150-T52	.78 mm ²	1 Φ mm	800 nm	50 A/W	2 nA	6 pF	150 V	.45 V/°C	100	65 / TO-52 or 66 / TO-52L	
APD15-8-150-TO5	1.77 mm ²	1.5 Φ mm	800 nm	50 A/W	5 nA	10 pF	150 V	.45 V/°C	100	67 / TO-5	
APD30-8-150-TO5	7 mm ²	3 Φ mm	800 nm	30 A/W	10 nA	40 pF	150 V	.45 V/°C	60	67 / TO-5	

APD50- 19.6 5 Φ mm 800 nm 20 A/W 30 nA 105 pF 150 V .45 V/°C 40 3 / TO-8
8-150- mm² TO8

* 'L' Suffix refers to devices with ball lens cap

No Photo

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Avalanche Photodiodes

Ultra High Gain Silicon Photodetectors

Silicon Avalanche Photodiodes make use of internal multiplication to achieve gain due to impact ionization. The result is the optimized series of high Responsivity devices, exhibiting excellent sensitivity. OSI Optoelectronics offers several sizes of detectors that are available with flat windows or ball lenses for optical fiber applications.

APPLICATIONS

- High Speed Optical Communications
- Laser Range Finder
- Bar Code Readers
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- Medical Equipment
- High Speed Photometry

FEATURES

- High Responsivity
- High Bandwidth / Fast Response
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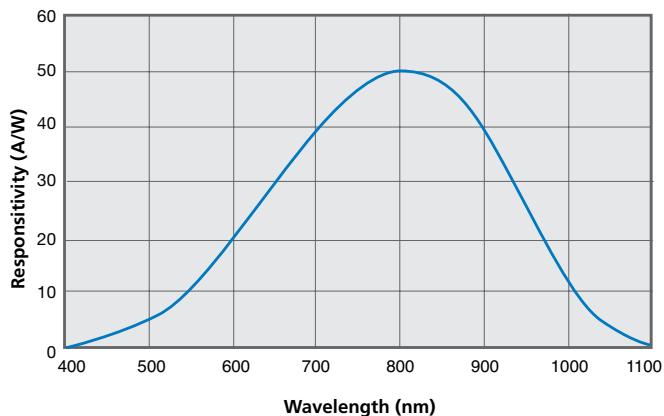
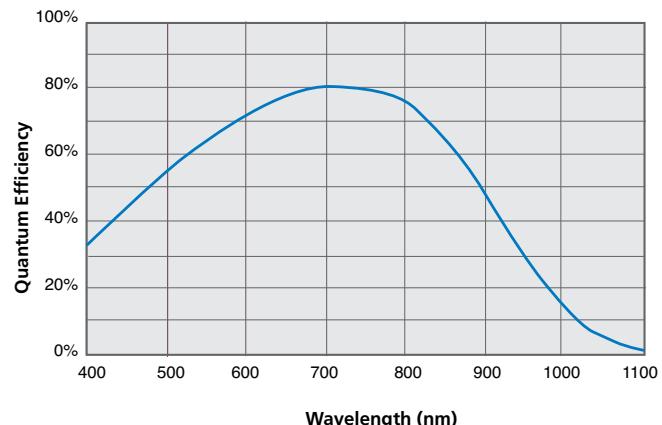
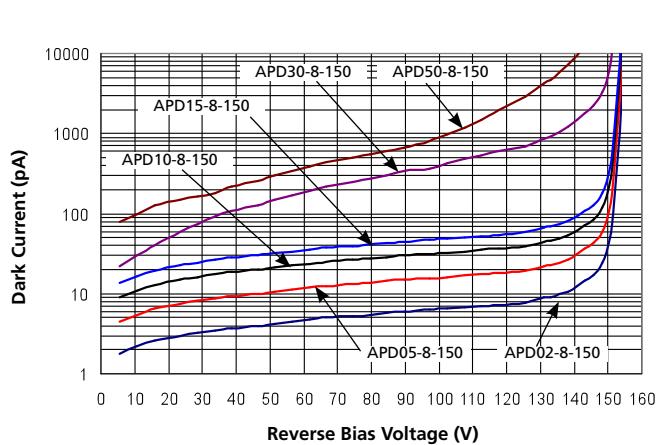
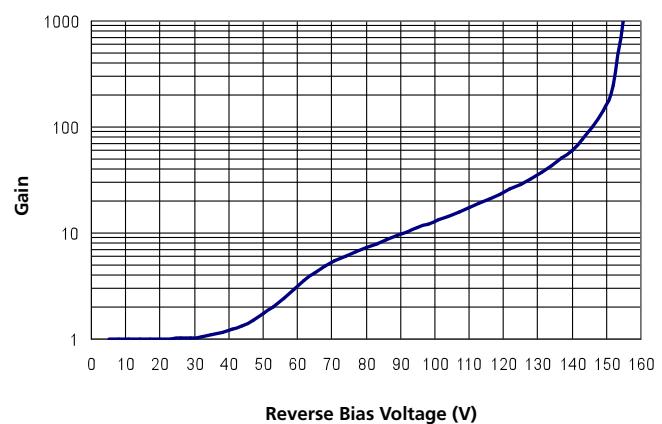
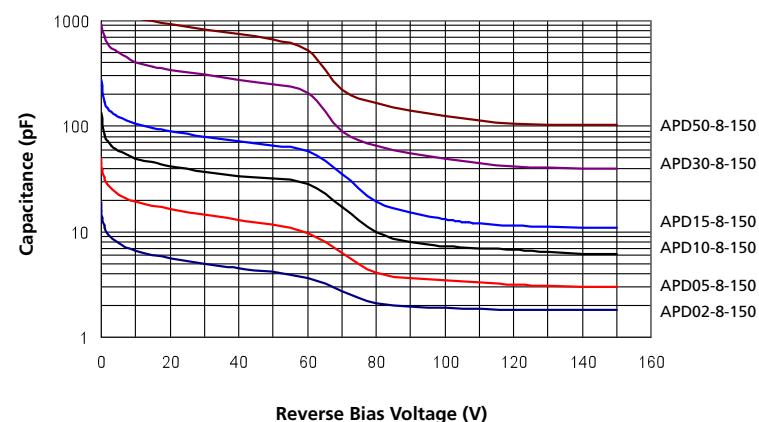


Electro-Optical Characteristics ($T_A = 23^\circ C$, typical values at gain listed, unless otherwise specified)

Product Model	Active Area		Responsivity @Gain M $\lambda = 800 \text{ nm}$ (A/W)	Dark Current Gain M (nA)		Ct Gain M (pF)	Q.E. M = 1 $\lambda = 800 \text{ nm}$ (%)	Breakdown Voltage 100μA (V)		Temperature Coefficient of Breakdown Voltage (V/°C)	Bandwidth -3dB Gain M $\lambda = 800 \text{ nm}$ (MHz)	Excess Noise Figure Gain M $\lambda = 800 \text{ nm}$	Gain M $\lambda = 800 \text{ nm}$	Storage Temperature (°C)	Operating Temperature (°C)	Package Style *2
	Diameter*1 (mm)	Area (mm ²)		Typ	Max			Typ	Max							
	Typ	Max		Typ	Max			Typ	Max							
APD02-8-150-T52	0.2	0.03	50	0.05	1	1.5	75	150	250	0.45	1000	0.3	100	-55 ~ +125	65 / TO-52 or 66 / TO-52L	65 / TO-52 or 66 / TO-52L
APD05-8-150-T52	0.5	0.19		0.1	1	3	75	150	250	0.45	900	0.3	100			
APD10-8-150-T52	1.0	0.78		0.2	2	6	75	150	250	0.45	600	0.3	100			
APD15-8-150-T05	1.5	1.77		0.5	5	10	75	150	250	0.45	350	0.3	100			
APD30-8-150-T05	3.0	7.0	30	1	10	40	75	150	250	0.45	65	0.3	60	-40 ~ +100	67 / TO-5	67 / TO-5
APD50-8-150-T08	5.0	19.6	20	3	30	105	75	150	250	0.45	25	0.3	40			3 / TO-8

*1: Area in which a typical gain can be obtained.

*2: Please refer to the Silicon APD brochure for more detailed information.
Cap with micro-lens is available for small active area size.

Typ. Spectral Response ($T_A = 23^\circ\text{C}$, $M = 100$)Typ. Quantum Efficiency vs. Wavelength ($T_A = 23^\circ\text{C}$)Typ. Dark Current vs. Reverse Bias ($T_A = 23^\circ\text{C}$)Typ. Gain vs. Reverse Bias ($T_A = 23^\circ\text{C}$, 800 nm)Typ. Capacitance vs. Reverse Bias ($T_A = 23^\circ\text{C}$, $f=1\text{MHz}$)

Photodiode Care and Handling Instructions

AVOID DIRECT LIGHT

Since the spectral response of silicon photodiode includes the visible light region, care must be taken to avoid photodiode exposure to high ambient light levels, particularly from tungsten sources or sunlight. During shipment from OSI Optoelectronics, your photodiodes are packaged in opaque, padded containers to avoid ambient light exposure and damage due to shock from dropping or jarring.

AVOID SHARP PHYSICAL SHOCK

Photodiodes can be rendered inoperable if dropped or sharply jarred. The wire bonds are delicate and can become separated from the photodiode's bonding pads when the detector is dropped or otherwise receives a sharp physical blow.

CLEAN WINDOWS WITH OPTICAL GRADE CLOTH / TISSUE

Most windows on OSI Optoelectronics photodiodes are either silicon or quartz. They should be cleaned with isopropyl alcohol and a soft (optical grade) pad.

OBSERVE STORAGE TEMPERATURES AND HUMIDITY LEVELS

Photodiode exposure to extreme high or low storage temperatures can affect the subsequent performance of a silicon photodiode. Storage temperature guidelines are presented in the photodiode performance specifications of this catalog. Please maintain a non-condensing environment for optimum performance and lifetime.

OBSERVE ELECTROSTATIC DISCHARGE (ESD) PRECAUTIONS

OSI Optoelectronics photodiodes, especially with IC devices (e.g. Photops) are considered ESD sensitive. The photodiodes are shipped in ESD protective packaging. When unpacking and using these products, anti-ESD precautions should be observed.

DO NOT EXPOSE PHOTODIODES TO HARSH CHEMICALS

Photodiode packages and/or operation may be impaired if exposed to CHLOROTHENE, THINNER, ACETONE, or TRICHLOROETHYLENE.

INSTALL WITH CARE

Most photodiodes in this catalog are provided with wire or pin leads for installation in circuit boards or sockets. Observe the soldering temperatures and conditions specified below:

Soldering Iron: Soldering 30 W or less
Temperature at tip of iron 300°C or lower.

Dip Soldering: Bath Temperature: 260±5°C.
Immersion Time: within 5 Sec.
Soldering Time: within 3 Sec.

Vapor Phase Soldering: DO NOT USE

Reflow Soldering: DO NOT USE

Photodiodes in plastic packages should be given special care. Clear plastic packages are more sensitive to environmental stress than those of black plastic. Storing devices in high humidity can present problems when soldering. Since the rapid heating during soldering stresses the wire bonds and can cause wire to bonding pad separation, it is recommended that devices in plastic packages to be baked for 24 hours at 85°C.

The leads on the photodiode **SHOULD NOT BE FORMED**. If your application requires lead spacing modification, please contact OSI Optoelectronics Applications group at (310)978-0516 before forming a product's leads. Product warranties could be voided.



*Most of our standard catalog products are RoHS Compliant. Please contact us for details

Mechanical Drawings

Mechanical Specifications and Die Topography

1. Parameter Definitions:

- A = Distance from top of chip to top of glass.
- a = Photodiode Anode.
- B = Distance from top of glass to bottom of case.
- c = Photodiode Cathode
- (Note: cathode is common to case in metal package products unless otherwise noted).
- W = Window Diameter.
- F.O.V. = Filed of View (see definition below).

2. Dimensions are in inches (1 inch = 25.4 mm).

3. Pin diameters are 0.018 ± 0.002 " unless otherwise specified.

4. Tolerances (unless otherwise noted)

General: $0.XX \pm 0.01"$
 $0.XXX \pm 0.005"$

Chip Centering: $\pm 0.010"$
 Dimension 'A': $\pm 0.015"$

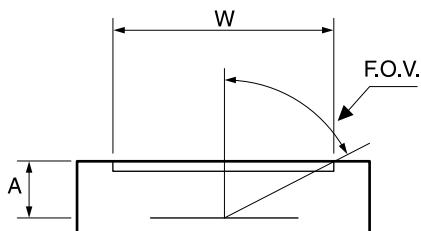
5. Windows

All 'UV' Enhanced products are provided with QUARTZ glass windows, 0.027 ± 0.002 " thick.

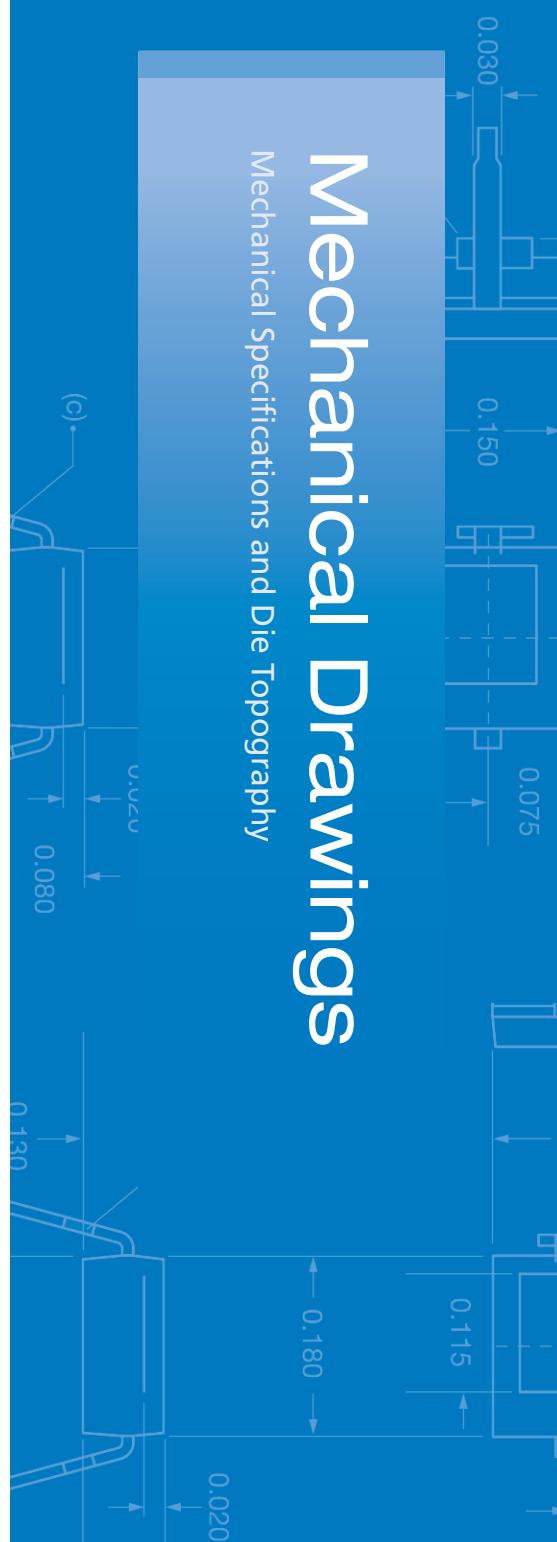
All 'XUV' products are provided with removable windows.

All 'DLS' PSD products are provided with A/R coated glass windows.

All 'FIL' photoconductive and photovoltaic products are epoxy filled instead of glass windows.



$$F.O.V. = \tan^{-1} \left(\frac{W}{2A} \right)$$



For Further Assistance
 Please Call One of Our Experienced
 Sales and Applications Engineers
310-978-0516

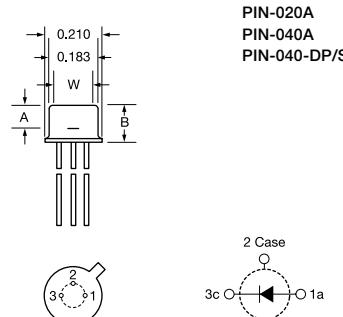
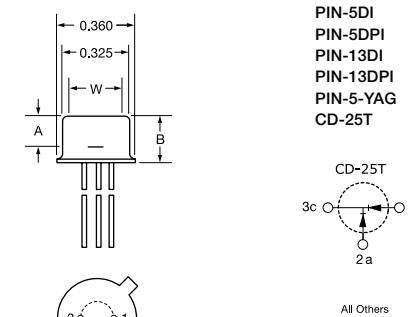
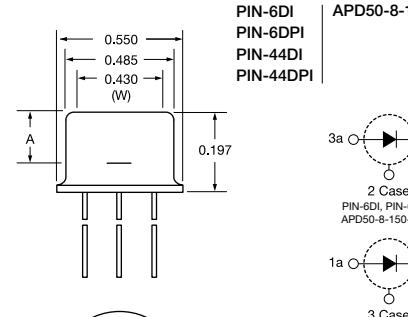
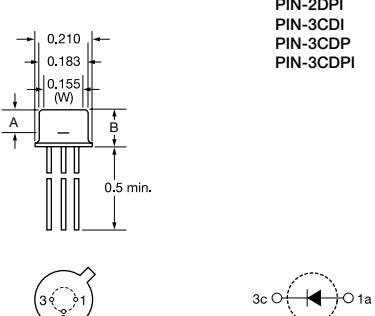
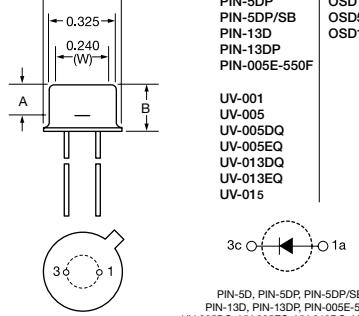
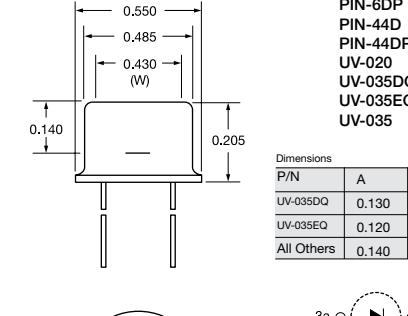
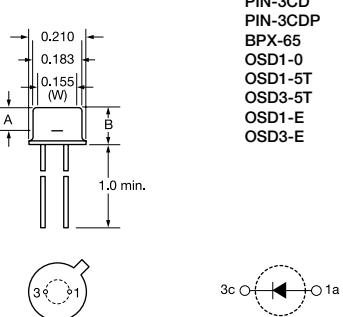
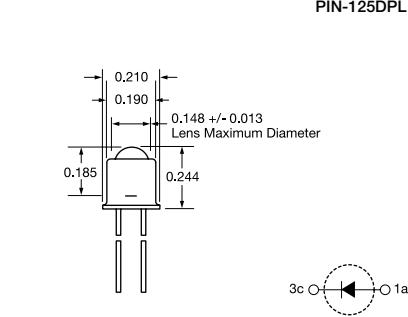
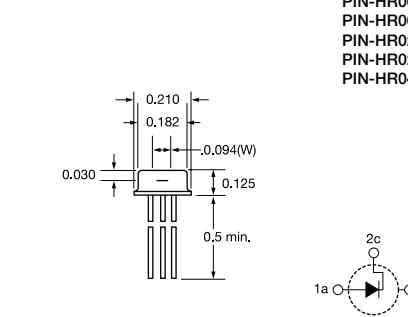
OSI Optoelectronics
 An OSI Systems Company



- Or -
 visit our website at
www.osiopptoelectronics.com

Mechanical Specifications

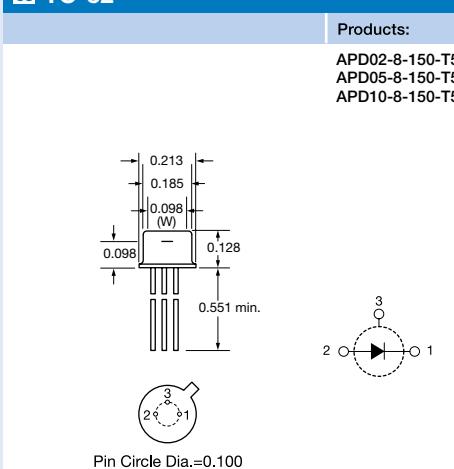
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1 TO-18	2 TO-5	3 TO-8																																																												
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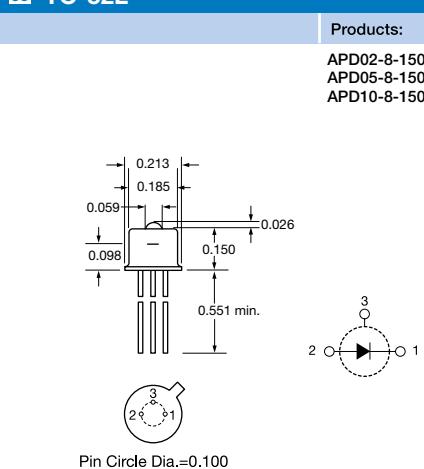
Mechanical Specifications

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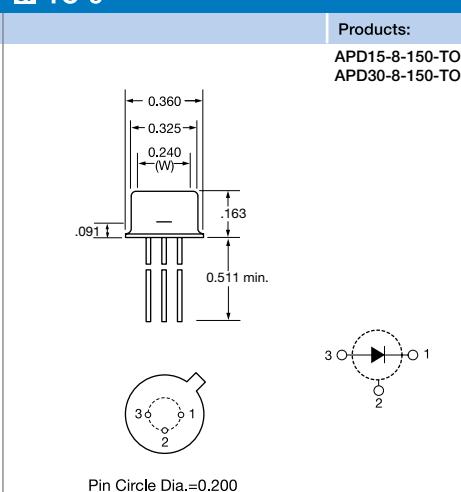
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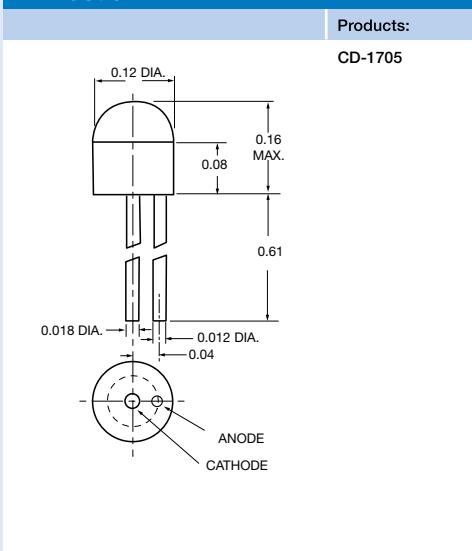
66 TO-52L



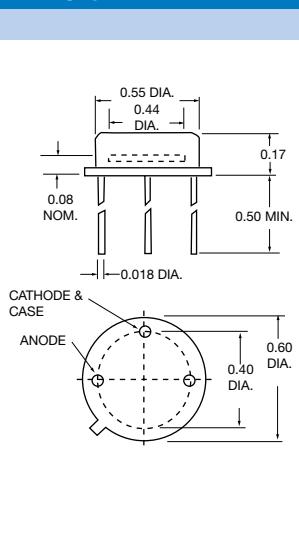
67 TO-5



68 Plastic



69 TO-8



70 TO-8

